技术数据表

[redacted]

特点（C ）：

*

High reliability High radiant intensity

目录

Catalog[redacted]

电性参数

✧极限参数 =25 ：Absolute Maximum Ratings (Temperature=25ÁC):

=25℃）

[redacted]

:

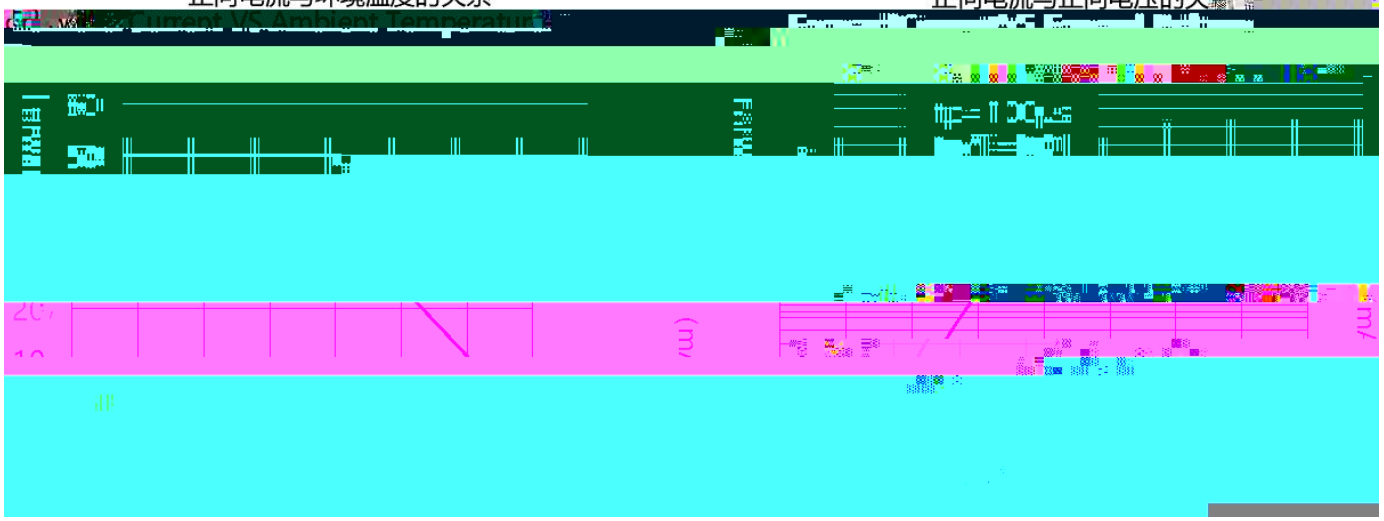
代码	最小值	最大值	[redacted]

[redacted]

典型特性曲线

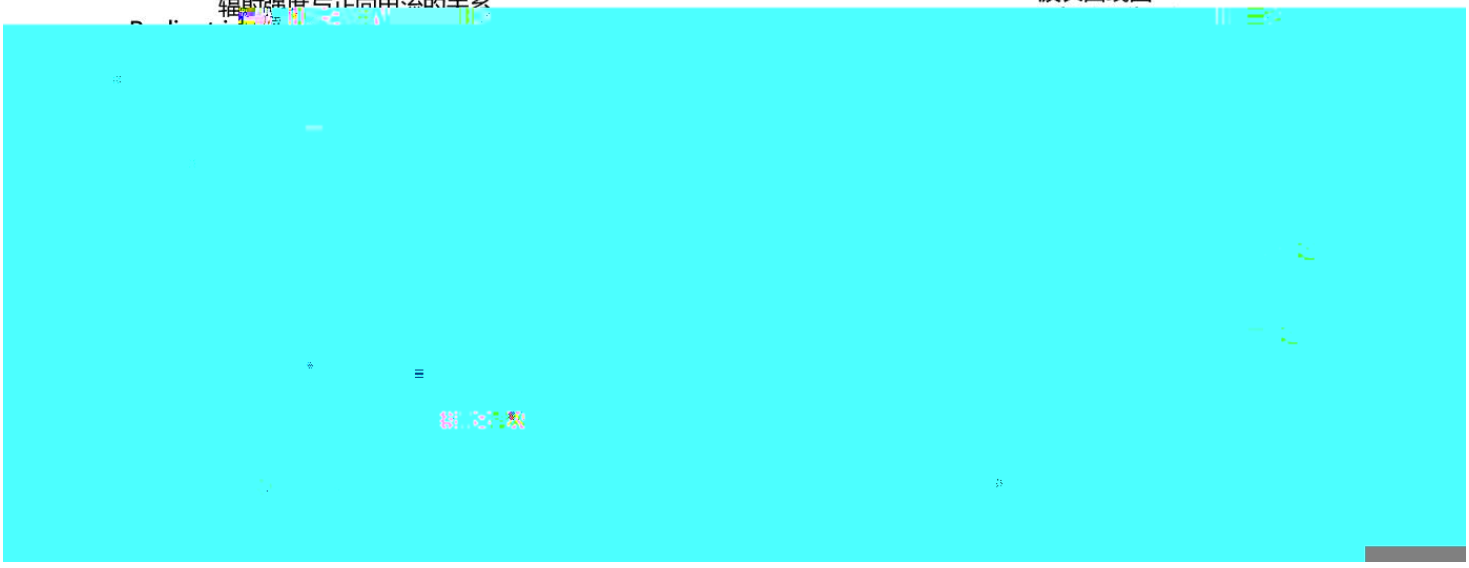
发射管特性曲线图

正向电流与环境温度的关系



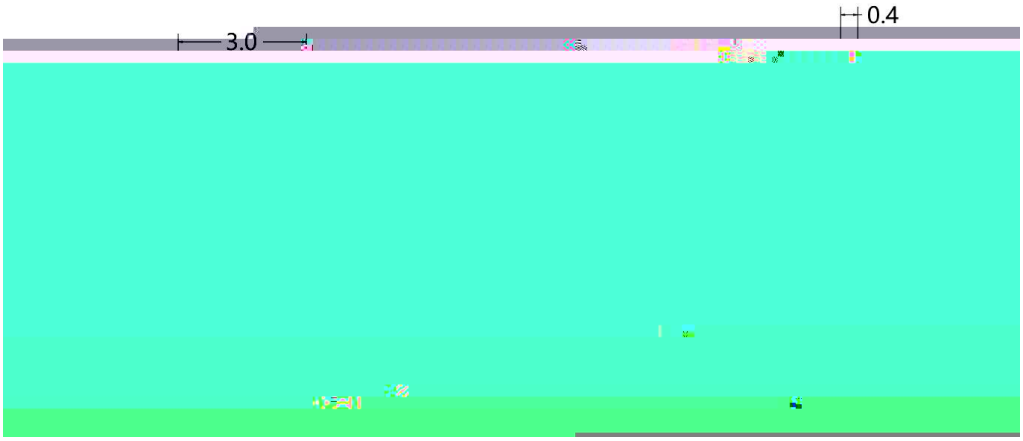
正向电流与正向电压的关系

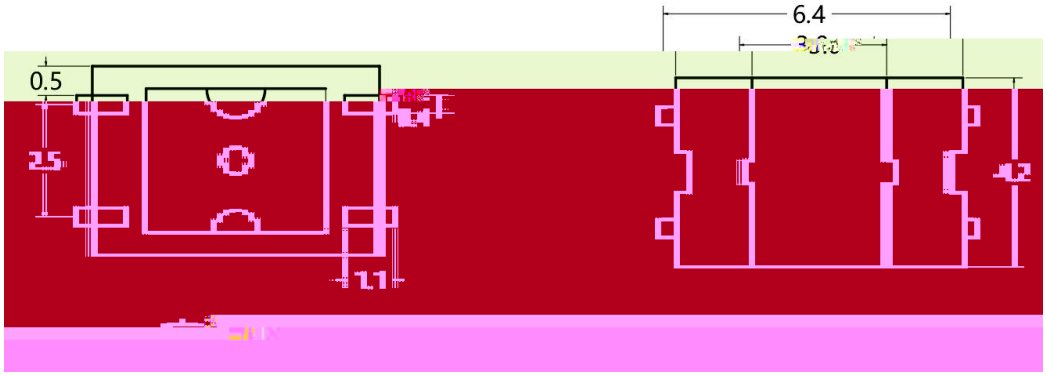
辐射强度与正向电流的关系

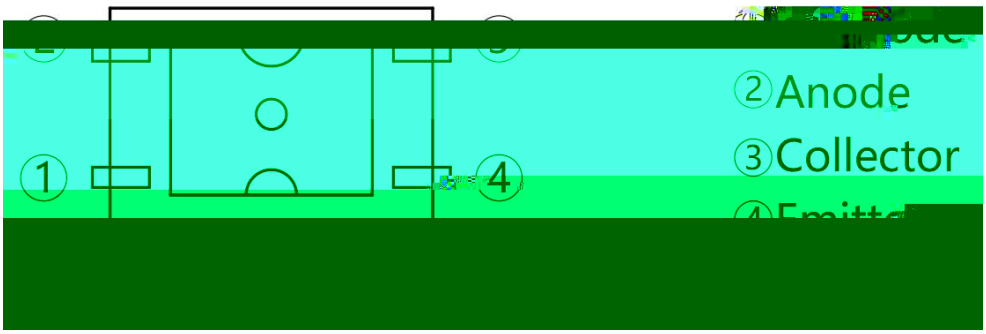


波长曲线图

外形尺寸







1. mm

Remarks: 1 Unit: mm

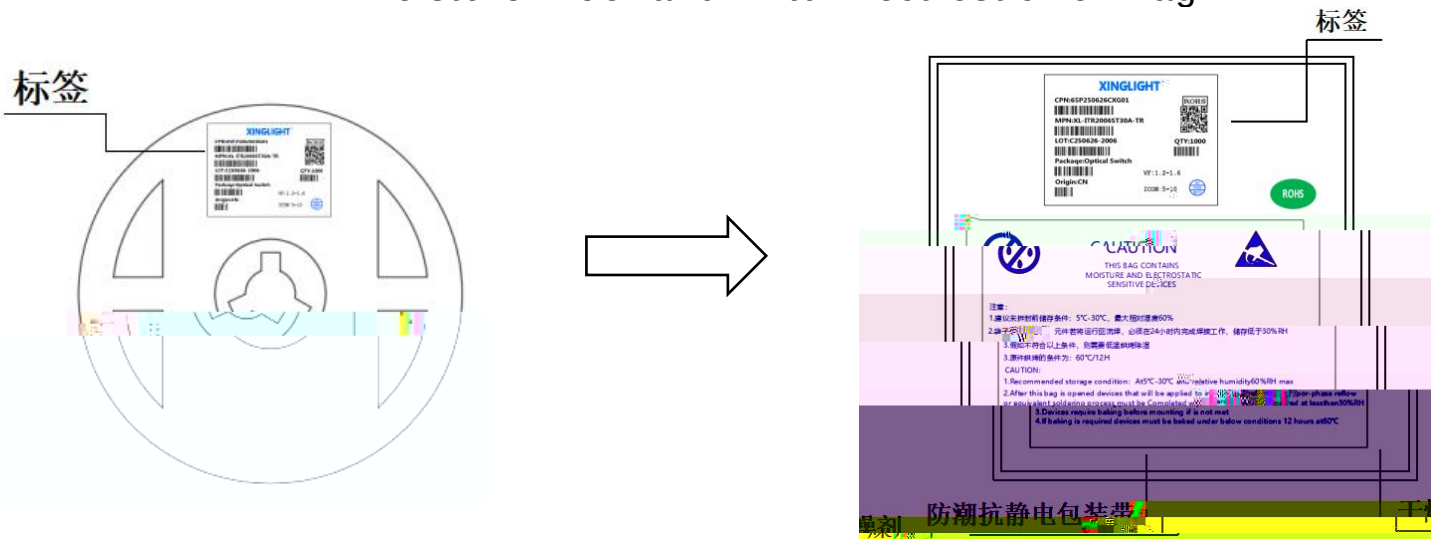
2. Ñ0.3mm

2. Tolerance: Ñ 0.3mm unless otherwise specified

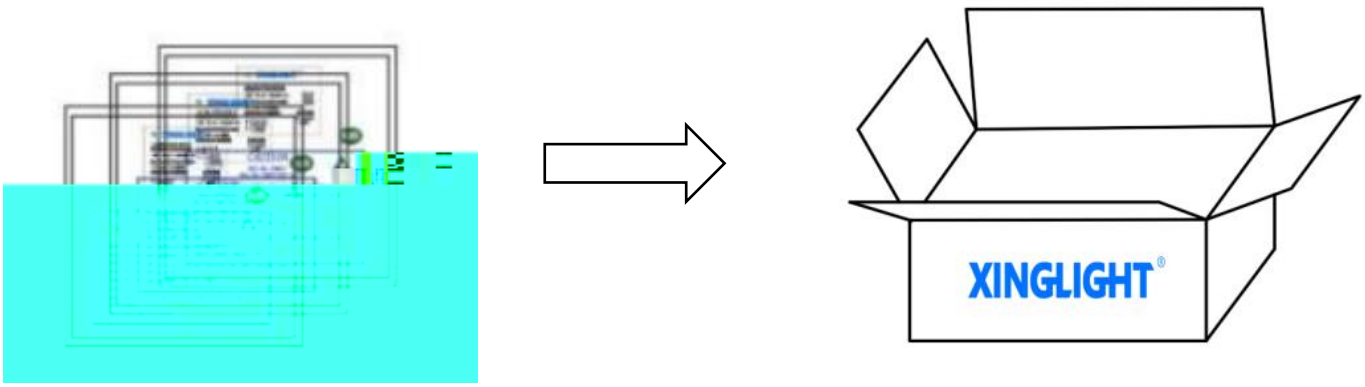
●Dimensions of Tape (Unit:

包装

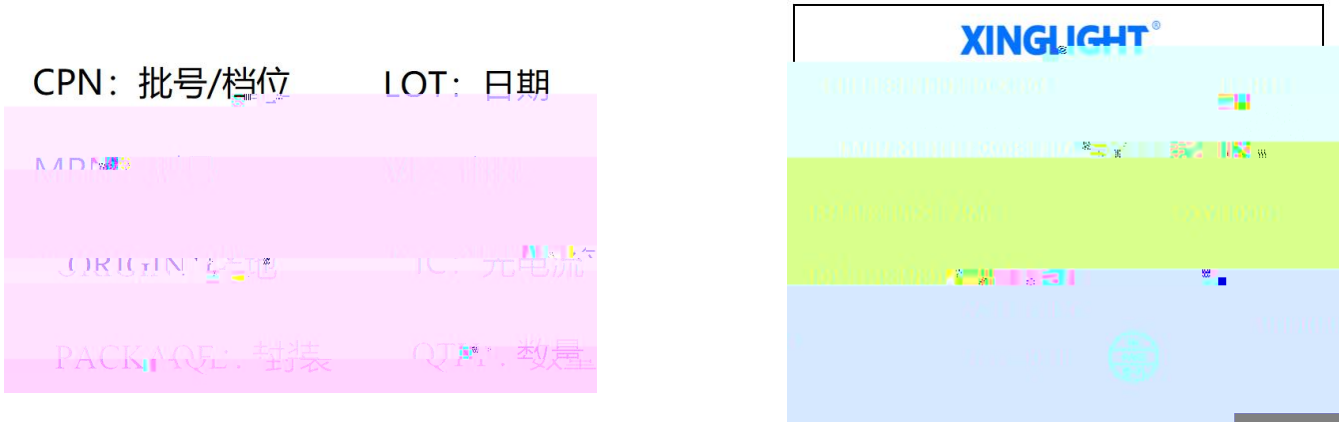
Moisture Proof and Antti-Electrostic Foil Bag



Cardboard Box

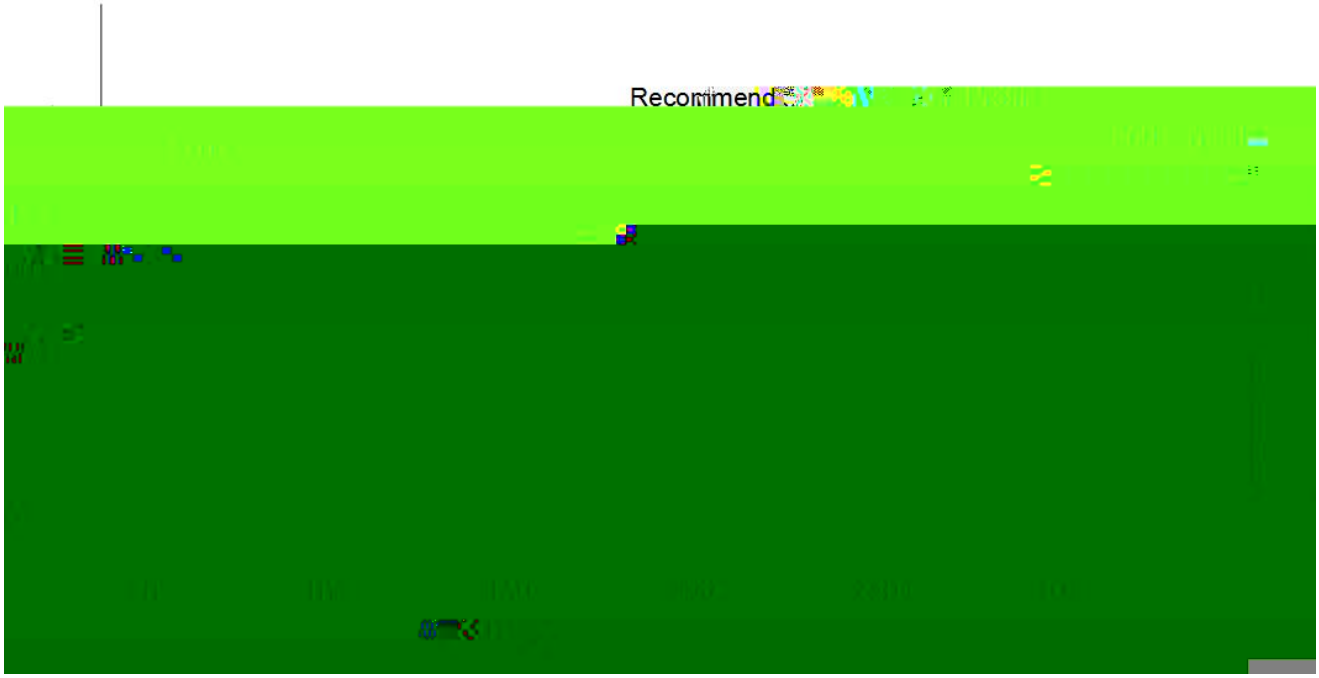


Label Expantion



焊接指导

The wave peak welding curve is recommended :



Note

1

Lead solder temperature profile

2

It is recommended to perform reflow soldering once

3 LED

When soldering, do not put stress on the LED during heating

4

After soldering, do

使用注意事项

NPN

IR

IR PT

This product It is composed of infrared emission diode and NPN silicon photo transistor, which are packaged side by side in black On the converging optical axis in the thermoplastic shell. Photo transistor only receives radiation from IR. This is normal Condition. But when the object is in the middle, the photo transistor cannot receive radiation. For more component information, please Refer to IR and PT.